DIO1268

Ultra Low On-Resistance Dual, SPDT Analog Switch

Features

- Switch Type: SPDT(2X)
- Voltage Operation: 1.6V to 4.2V
- Ultra-Low On Resistance: 0.75Ω @ 4.2V
- -3dB Bandwidth: 75MHz
- High Off-isolation: -78dB@100kHz
- Low Crosstalk: -100dB@100kHz
- Excellent On Resistance Matching: 0.03Ω
- Low Total Harmonic Distortion (THD)
- Rail-to-Rail Input and Output Operation
- Break-Before-Make Switching
- Green Packaged: 10-DQFN, QFN-10
- 5kV HBM ESD

Descriptions

The DIO1268 is a dual Single-Pole, Double-Throw (SPDT) analog switch. DIO1268 operates from a single 1.6V to 4.2V supply and features an ultra-low on resistance of 0.75Ω at a 4.2V supply and T_A = 25°C. This device is fabricated with sub-micron CMOS technology to achieve fast switching speeds and is designed for break-before-make operation.

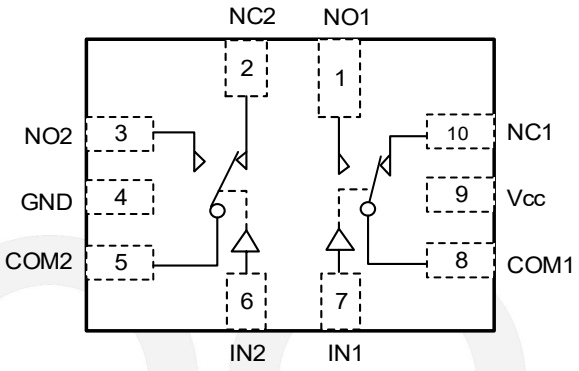
DIO1268 guarantees 0.03Ω on-resistance matching between switches, on-resistance flatness over the signal range, high off-isolation and low crosstalk, which ensures excellent linearity and low distortion when switching audio signals. DIO1268 consists of two normally open and two normally close switches.

DIO1268 provides packages with Green 10-lead DQFN, 10-lead QFN.

Applications

- Cell-Phone/PDA
- MP3/MP4/PMP
- Portable Instrumentation
- Battery Powered Communications
- Computer Peripherals

Block Diagram

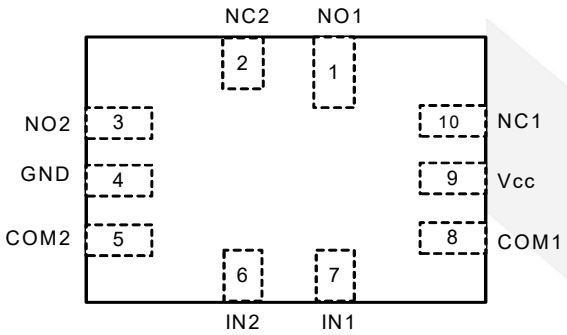


Ordering Information

Order Part Number	Top Marking		T_A	Package	
DIO1268LP10	YWGA	Green	-40 to 85°C	DQFN-10	Tape & Reel, 3000
DIO1268QN10	YWGA	Green	-40 to 85°C	QFN-10	Tape & Reel, 3000

Pin Assignment

DQFN-10



QFN-10

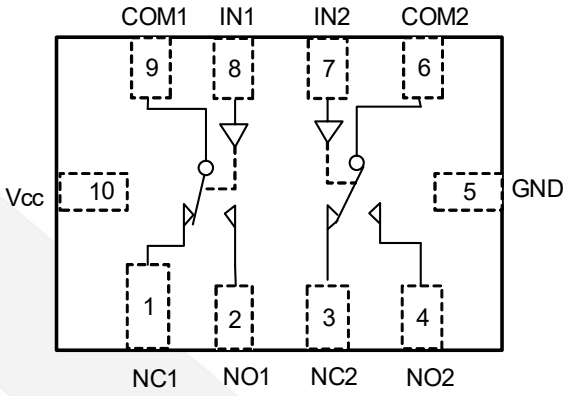


Figure 1 Top View

Pin Descriptions

Pin Name	Description
V_{CC}/GND	Power Supply
IN1, IN2	Digital control pin to connect the COM terminal to the NO or NC terminals
COM1, COM2	Common terminal
NO1, NO2	Normally-open terminal
NC1, NC2	Normally-closed terminal

Truth Table

IN1, IN2	NO	NC
L	OFF	ON
H	ON	OFF

Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Rating” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	-0.3	4.6	V
V_{CNTRL}	DC input Voltage	-0.3	(V_{CC}) + 0.3	V
V_{SW}	DC input I/O Voltage	-0.3	(V_{CC}) + 0.3	V
I_{IK}	DC input Diode current		-50	mA
T_{STG}	Storage Temperature	-65	150	°C
ESD	HBM, JEDEC: JESD22-A114		5000	V
	CDM, JEDEC : JESD22-C101		2000	

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply voltage	1.6	4.2	V
V_{CNTRL}	Control input voltage (IN1/IN2)	0	V_{CC}	V
V_{SW}	Switch I/O voltage	0	V_{CC}	V
T_A	Operating Temperature	-40	85	°C

Electrical Characteristics

All typical value are at V_{CC}=4.2V, GND=0V, V_{IH}=1.5V, V_{IL}=0.5V, T_A=25°C unless otherwise specified.

Symbol	Parameter	Conditions	V_{CC}/V	Temp	Min	Typ	Max	Unit
Analog Switch Characteristics								
R_{ON}	On-Resistance	V_{NO}, V_{NC}, or V_{COM}=1V, I_{COM}= -100mA	4.2	25°C		0.75	0.85	Ω
				-40 to 85°C			0.95	Ω
ΔR_{ON}	On-Resistance Match Between Channels	V_{NO}, V_{NC} or V_{COM}=1V, I_{COM}= -100mA	4.2	25°C		0.03	0.15	Ω
				-40 to 85°C			0.20	Ω
$R_{FLAT(ON)}$	On-Resistance Flatness	V_{NO}, V_{NC} or V_{COM}=1V, 2.5V I_{COM}= -100mA	4.2	25°C		0.15	0.23	Ω
				-40 to 85°C			0.30	Ω
$I_{NC(OFF)}$, $I_{NO(OFF)}$	Source OFF Leakage Current	V_{NO}, V_{NC}=3.3V, 0.3V V_{COM}= 0.3V/3.3V	4.2	-40 to 85°C			50	nA
$I_{NC(ON)}$, $I_{NO(ON)}$ $I_{COM(ON)}$	Channel ON Leakage Current	V_{NO}, V_{NC}=3.3V, 0.3V or floating V_{COM}= 0.3V/3.3V	4.2	-40 to 85°C			50	nA
Digital Inputs								
V_{INH}	Input High Voltage			-40 to 85°C	1.5			V
V_{INL}	Input Low Voltage			-40 to 85°C			0.5	V
I_{IN}	Input Leakage Current	V_{CC}=4.2V, V_{IN}=0V, or 4.2V		-40 to 85°C			1	μA
Dynamic Characteristics								
t_{ON}	Turn-On Time	V_{IN}=2.1V to 0V, R_L=50 Ω, C_L=35pF, V_{NO1} or V_{NO2} or V_{NC2}=2.1V		25°C		25		ns
t_{OFF}	Turn-Off Time	V_{IN}=2.1V to 0V, R_L=50 Ω, C_L=35pF, V_{NO1} or V_{NO2} or V_{NC2}=2.1V		25°C		35		ns

t_D	Break-Before-Make Time Delay	V_{IN}=2.1V to 0V, R_L=50 Ω, C_L=35pF, V_{NO1} or V_{NO2} or V_{NC2}=2.1V			25°C		45		ns
O_{ISO}	Off Isolation	V_{BIAS}=2.1V, Signal=0dBm	100kHz		25°C		-78		dB
			1MHz				-58		
X_{TALK}	Channel-to-Channel Crosstalk	V_{BIAS}=2.1V, Signal=0dBm	100kHz		25°C		-100		dB
			1MHz				-75		
BW	-3dB Bandwidth	V_{BIAS}=2.1V, Signal=0dBm			25°C		75		MHz
THD	Total Harmonic Distortion	f=20Hz to 20kHz, R_L=32Ω, V_{SW}=1V_{PP}			25°C		0.02		%
Q	Charge Injection Select Input to Common I/O	V_G=0V, R_S=0 Ω, C_L=1.0nF			25°C		4.0		pC
C_{ON}	Channel ON Capacitance				25°C		106		pF

Electrical Characteristics

All typical value are at V_{CC}=4.2V, GND=0V, V_{IH}=1.5V, V_{IL}=0.5V, T_A=25°C unless otherwise specified.

Symbol	Parameter	Conditions	V_{CC}/V	Temp	Min	Typ	Max	Unit
Power Requirements								
V_{CC}	Power Supply Range			-40 to 85°C	1.6		4.2	V
I_{CC}	Quiescent Supply Current	V_{IN}=0V or V_{CC}	4.2	-40 to 85°C			500	nA
I_{CCT}	Increase in I_{CC} per Input	Input at 2.6V	4.2	-40 to 85°C			5	μA
		Input at 1.6V					15	

Specifications subject to change without notice.

Test Diagrams

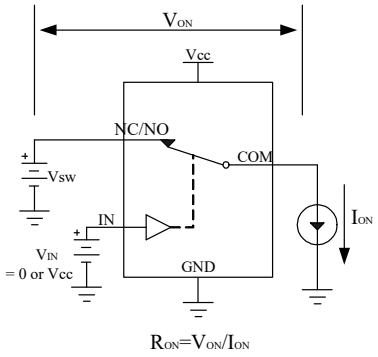


Figure 2 Switch on resistor

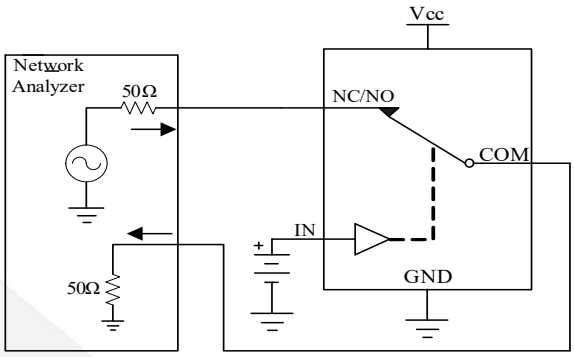


Figure 5 Bandwidth

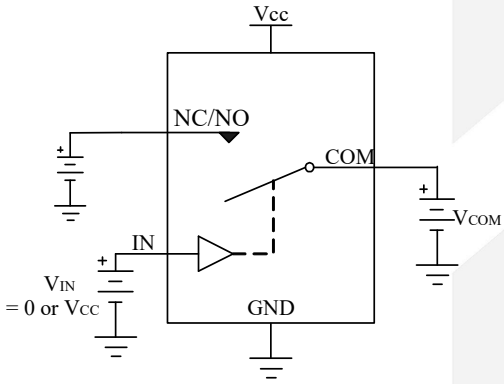


Figure 3 Switch Off Leakage

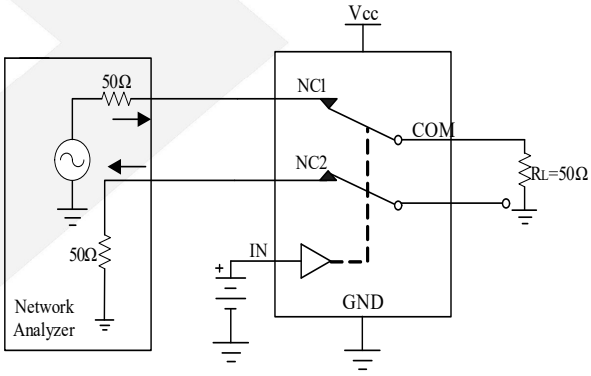


Figure 6 Channel-to-channel crosstalk

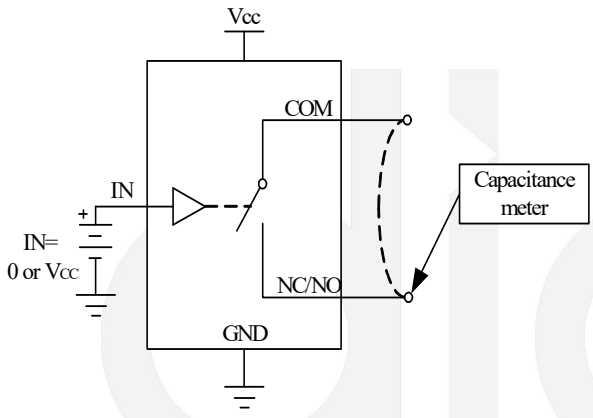


Figure 4 On/off Capacitance test

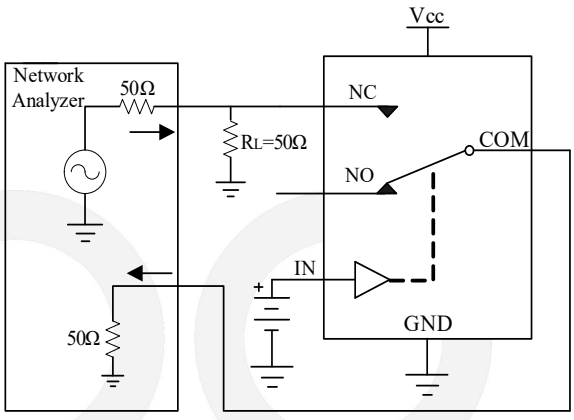
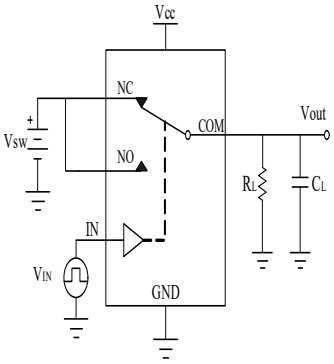


Figure 7 Off-isolation



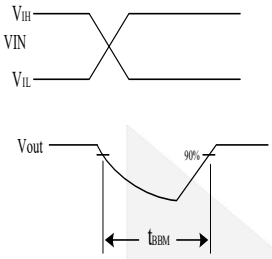
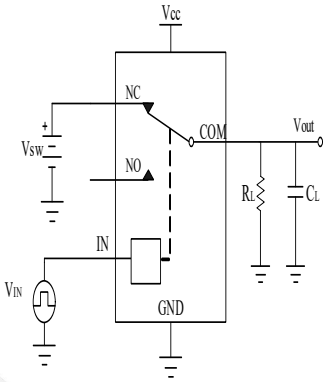


Figure 8 Break-Before-Make



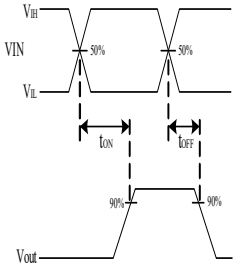
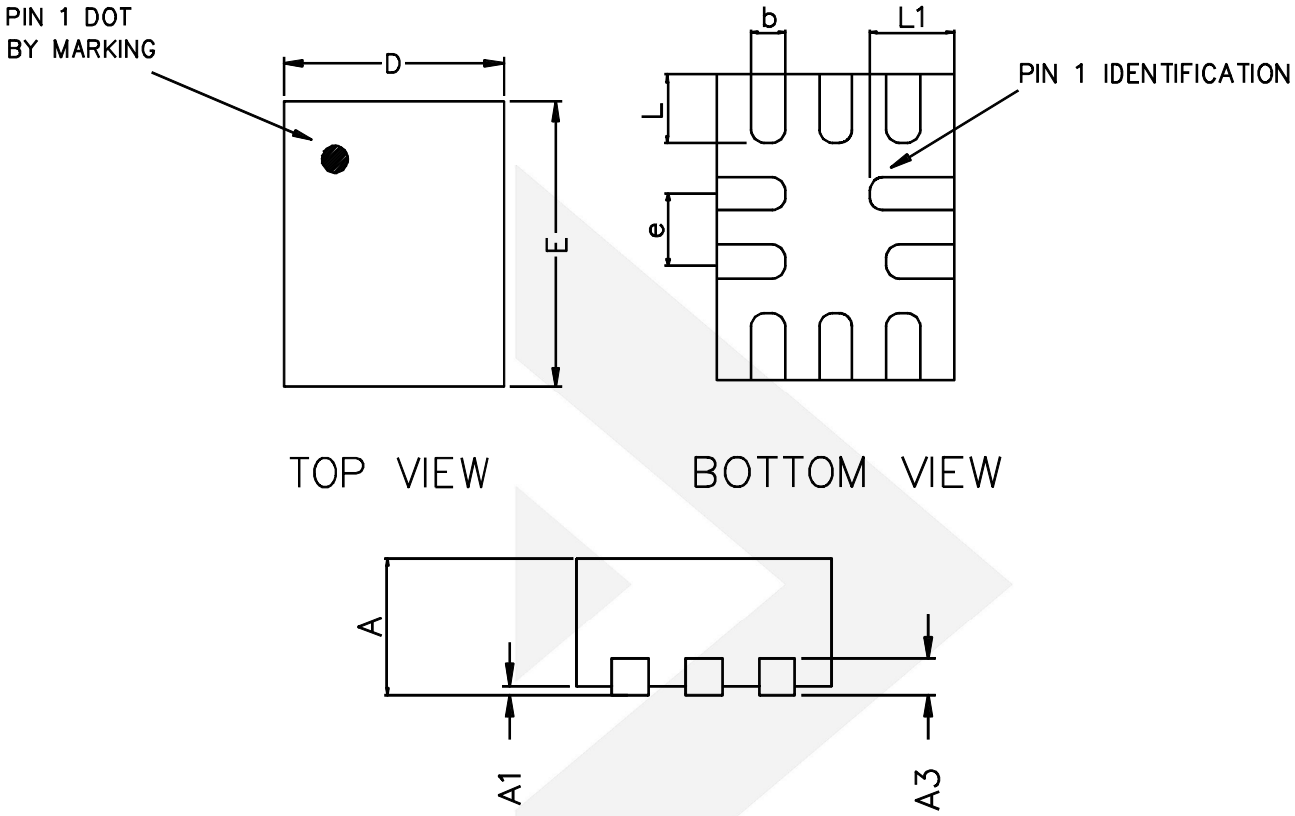


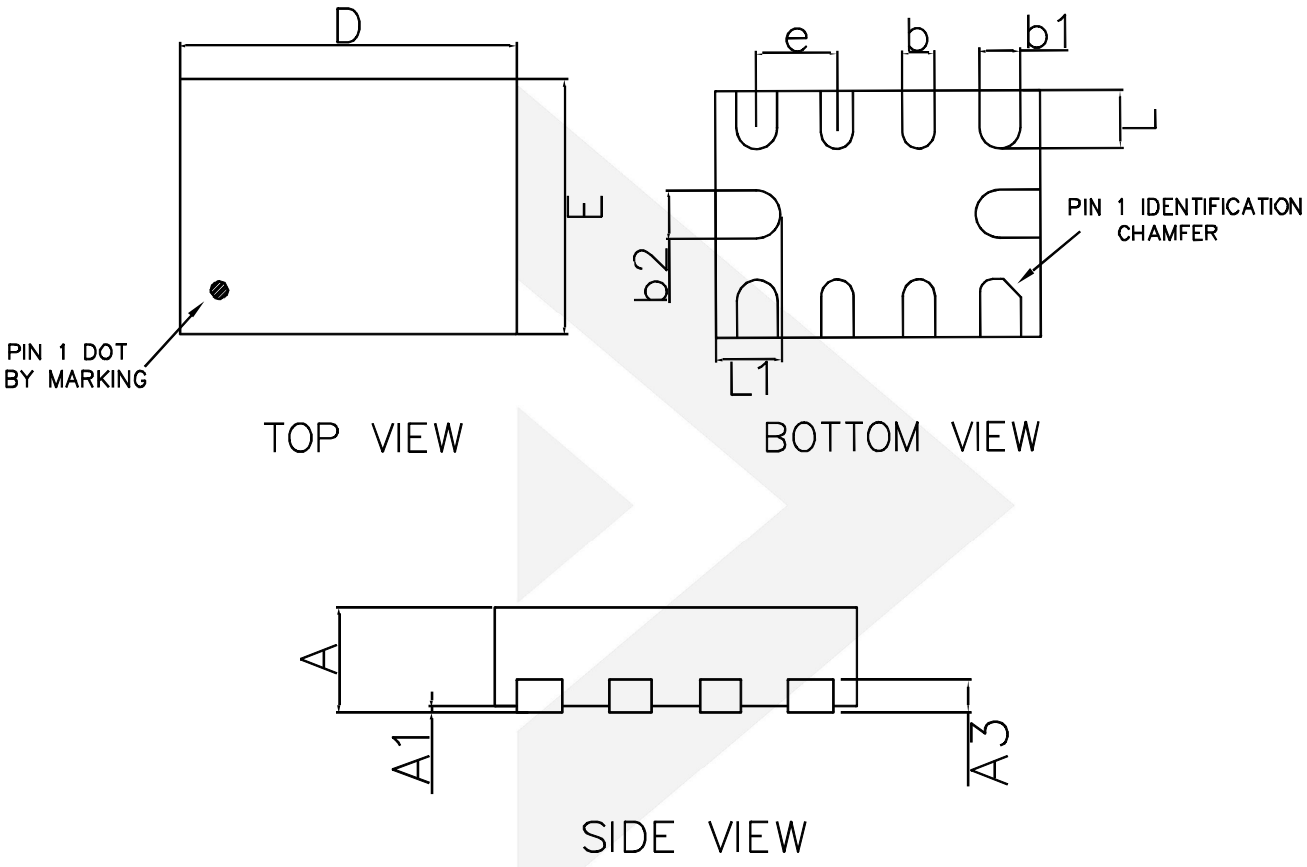
Figure 9 Turn-On/Turn-Off

Physical Dimensions: DQFN-10



COMMON DIMENSIONS(MM)			
PKG.	UT:ULTRA THIN		
REF	MIN	NOM	MAX
A	0.50	0.55	0.60
A1	0.00	--	0.05
A3	0.15REF.		
D	1.35	1.40	1.45
E	1.75	1.80	1.85
b	0.15	0.20	0.25
L	0.30	0.40	0.50
L1	0.40	0.50	0.60
e	0.40BSC		

Physical Dimensions: QFN-10



COMMON DIMENSIONS (UNITS OF MEASURE=MM)			
Symbol	**MIN**	**NOM**	**MAX**
A	0.50	0.55	0.60
A1	0.00	-	0.05
A3		0.15REF	
D	1.95	2.00	2.05
E	1.45	1.50	1.55
b	0.15	0.20	0.25
b1	0.20	0.25	0.30
b2	0.25	0.30	0.35
L	0.30	0.35	0.40
L1	0.35	0.40	0.45
e		0.50 BSC	

CONTACT US

Dioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as, cell phone, handheld products, laptop, and medical equipment and so on. Dioo's product families include analog signal processing and amplifying, LED drivers and charger IC. Go to http://www.dioo.com for a complete list of Dioo product families.

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